

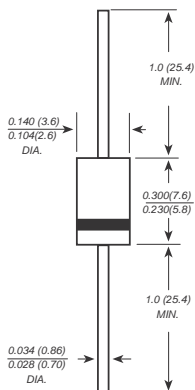


# 1N5391 THRU 1N5399

## GENERAL PURPOSE SILICON RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.5Amperes

### DO-15



Dimensions in inches and (millimeters)

### FEATURES

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ Construction utilizes void-free molded plastic technique
- ◆ Low reverse leakage
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:  
250°C/10 seconds, 0.375" (9.5mm) lead length, 5 lbs. (2.3kg) tension

### MECHANICAL DATA

**Case:** JEDEC DO-15 molded plastic body  
**Terminals:** Plated axial leads, solderable per MIL-STD-750, Method 2026  
**Polarity:** Color band denotes cathode end  
**Mounting Position:** Any  
**Weight:** 0.014 ounce, 0.40 grams

### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.  
 Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

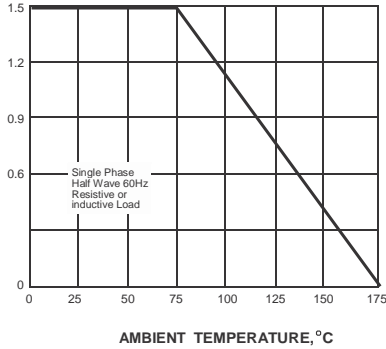
	SYMBOLS	1N 5391	1N 5392	1N 5393	1N 5394	1N 5395	1N 5396	1N 5397	1N 5398	1N 5399	UNITS
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	300	400	500	600	800	1000	VOLTS
Maximum RMS voltage	$V_{RMS}$	35	70	140	210	280	350	420	560	700	VOLTS
Maximum DC blocking voltage	$V_{DC}$	50	100	200	300	400	500	600	800	1000	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=75\text{ C}$	$I_{(AV)}$	1.5									Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	$I_{FSM}$	50.0									Amps
Maximum instantaneous forward voltage at 1.5A	$V_F$	1.4									Volts
Maximum DC reverse current $T_A=25\text{ C}$ at rated DC blocking voltage $T_A=100\text{ C}$	$I_R$	50.0									$\mu\text{A}$
Typical junction capacitance (NOTE 1)	$C_J$	20.0									pF
Typical thermal resistance (NOTE 2)	$R_{JA}$	50.0									C/W
Operating junction and storage temperature range	$T_J, T_{STG}$	-65 to +175									C

**Note:** 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.  
 2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted

# RATINGS AND CHARACTERISTIC CURVES 1N5391 THRU 1N5399

AVERAGE FORWARD RECTIFIED CURRENT,  
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



PEAK FORWARD SURGE CURRENT,  
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

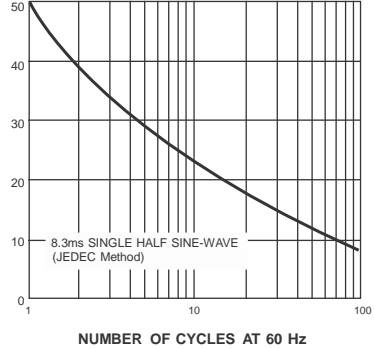


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

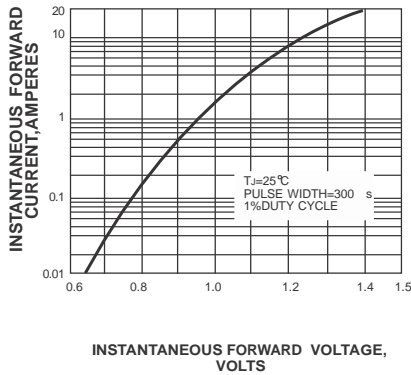
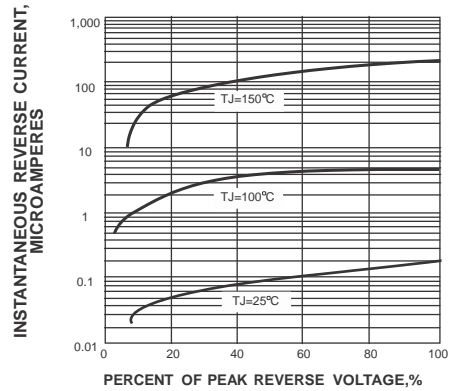
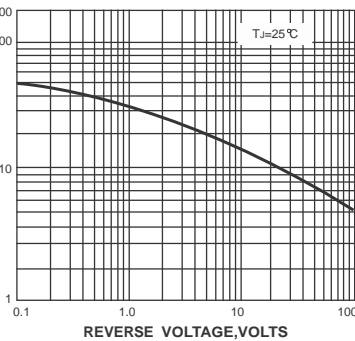


FIG. 4-TYPICAL REVERSE CHARACTERISTICS



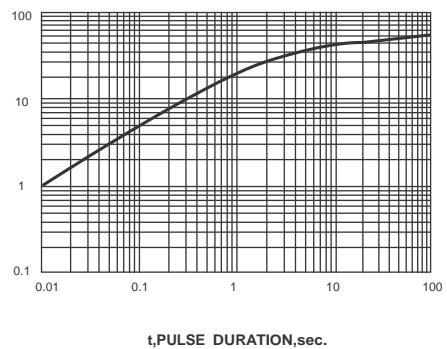
JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,  
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



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